

Ordering number : ENN7179A

P-Channel Silicon MOSFET

2SJ615



Ultrahigh-Speed Switching Applications

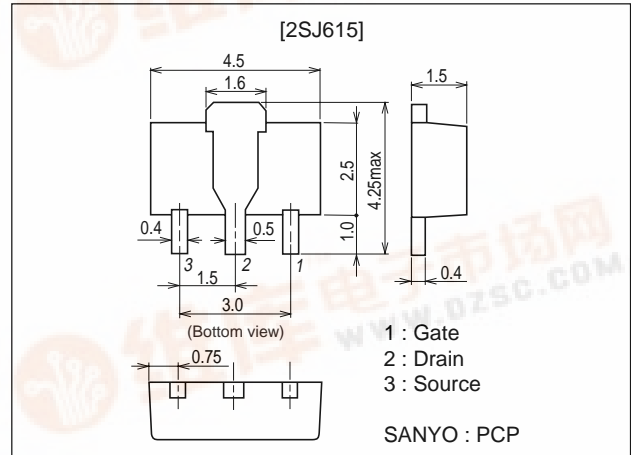
Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

Package Dimensions

unit : mm

2062A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-30	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		-2.5	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-10	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (250mm ² X0.8mm)	1.0	W
		Tc=25°C	3.5	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =-1mA, V _{GS} =0	-30			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0			-1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-1.3A	1.1	1.6		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-1.3A, V _{GS} =-10V		210	270	mΩ
	R _{DS(on)2}	I _D =-0.7A, V _{GS} =-4V		330	460	mΩ

Marking : JV

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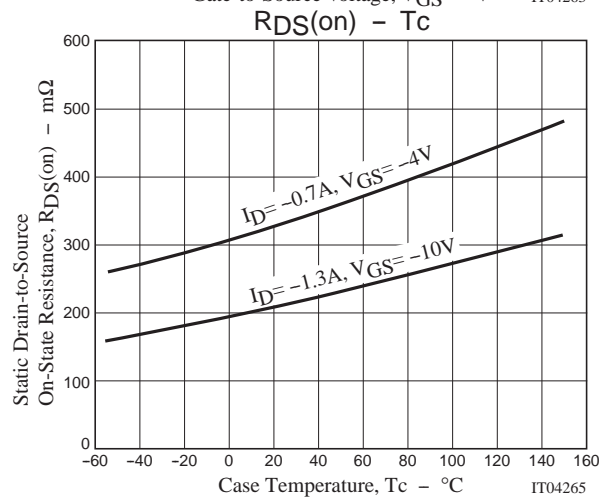
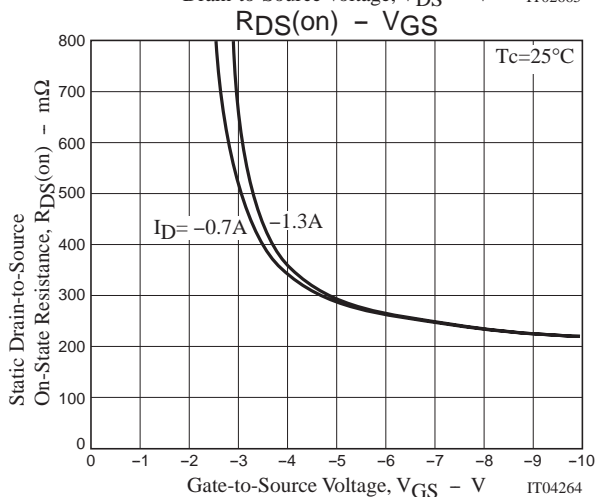
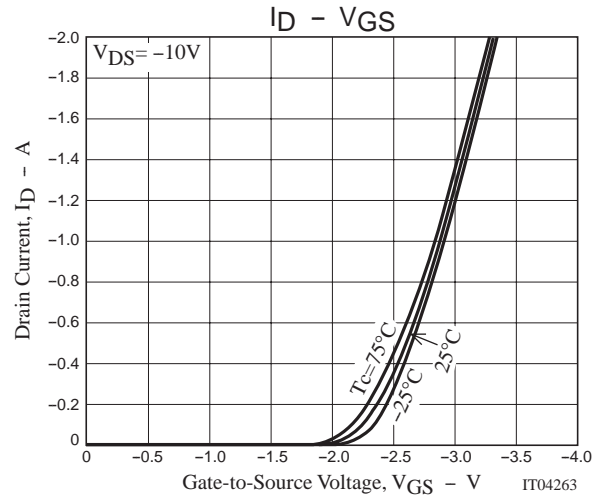
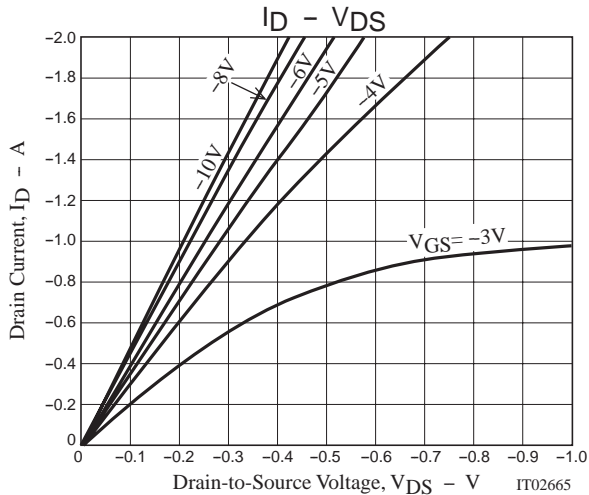
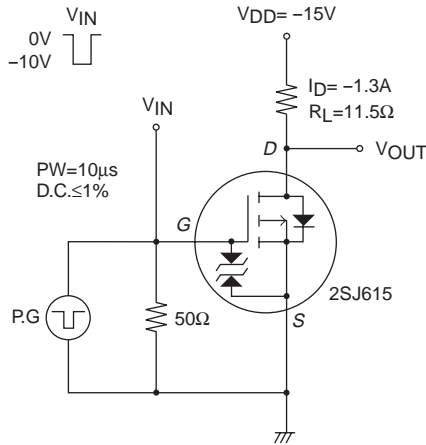


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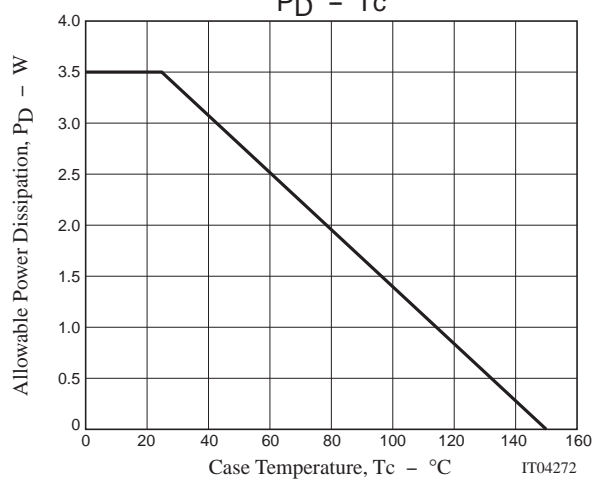
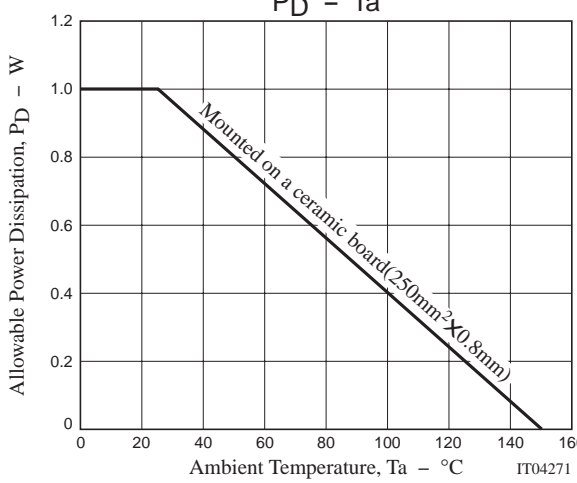
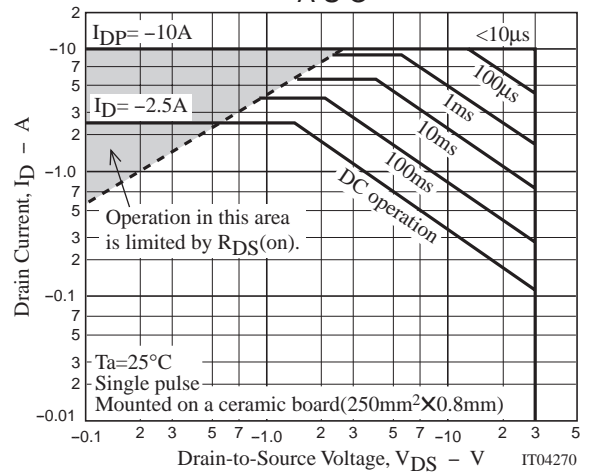
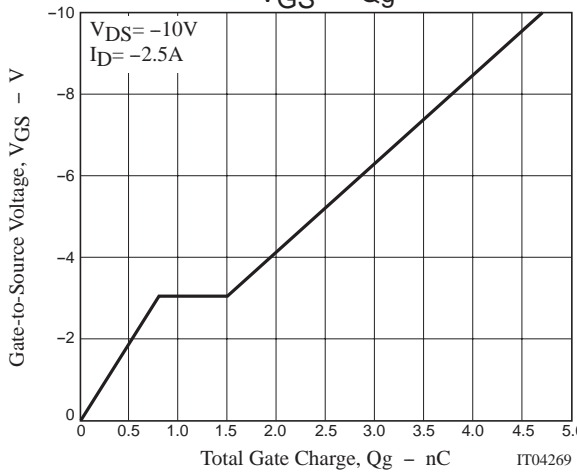
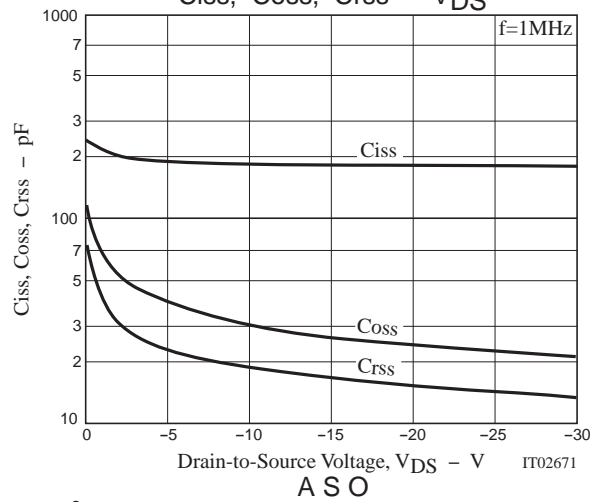
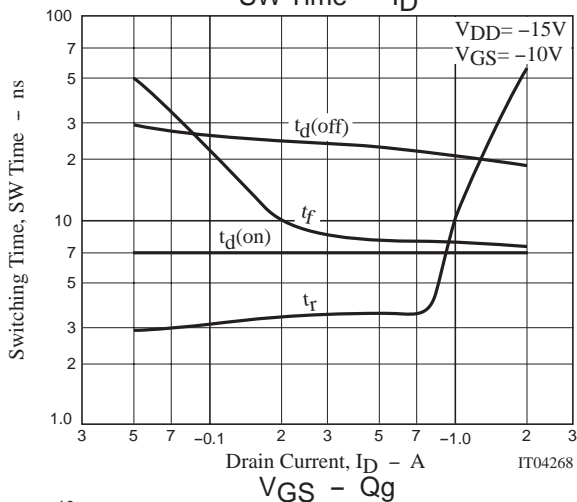
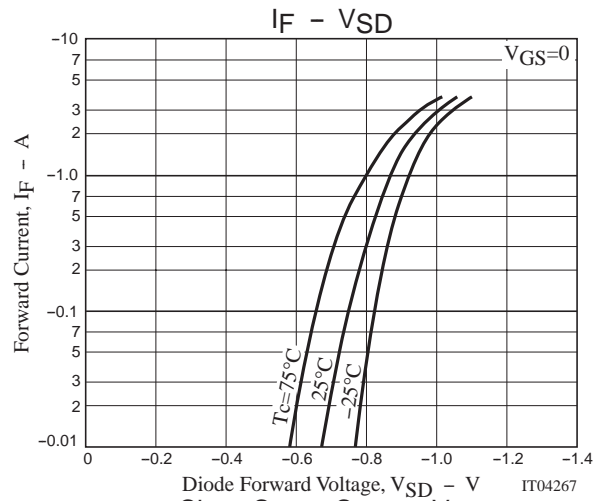
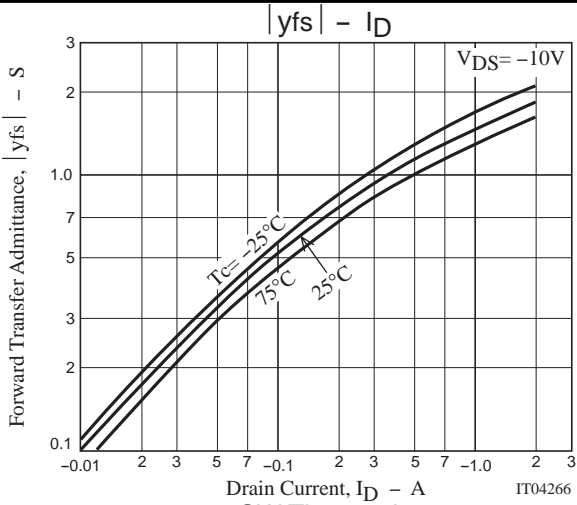
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	$V_{DS}=-10V, f=1MHz$		185		pF
Output Capacitance	Coss	$V_{DS}=-10V, f=1MHz$		30		pF
Reverse Transfer Capacitance	Crss	$V_{DS}=-10V, f=1MHz$		20		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		7		ns
Rise Time	t_r	See specified Test Circuit.		22		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		19		ns
Fall Time	t_f	See specified Test Circuit.		7.5		ns
Total Gate Charge	Qg	$V_{DS}=-10V, V_{GS}=-10V, I_D=-2.5A$		4.7		nC
Gate-to-Source Charge	Qgs	$V_{DS}=-10V, V_{GS}=-10V, I_D=-2.5A$		0.8		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=-10V, V_{GS}=-01V, I_D=-2.5A$		0.7		nC
Diode Forward Voltage	V_{SD}	$I_S=-2.5A, V_{GS}=0$	-0.97		-1.5	V

Switching Time Test Circuit



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